# SGS-THOMSON MICROELECTRONICS

TDA8176

## TV VERTICAL DEFLECTION SYSTEM FOR TV AND MONITORS

- SYNCHRONIZATION CIRCUIT
- OSCILLATOR AND RAMP GENERATOR
- HIGH POWER GAIN AMPLIFIER
- FLYBACK GENERATOR
- VOLTAGE REGULATOR
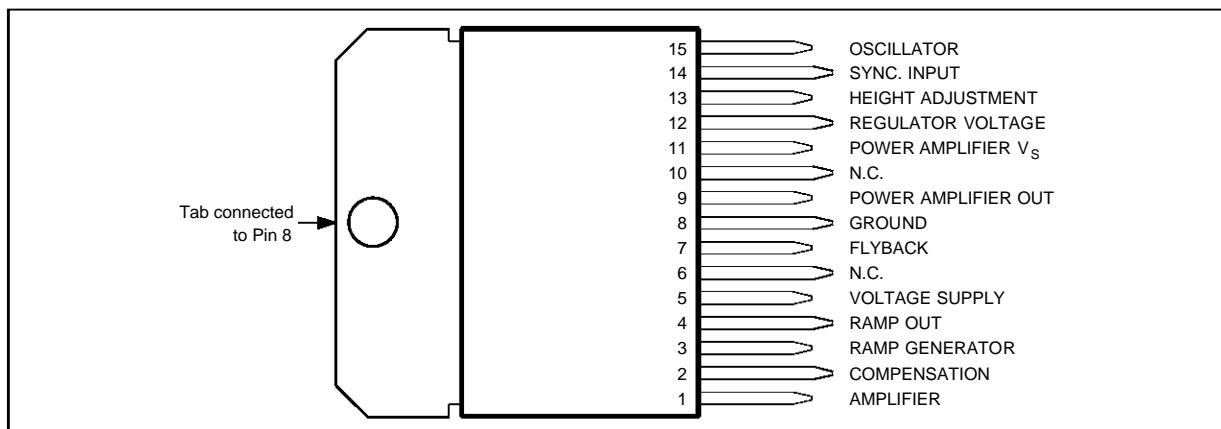
MULTIWATT 15
(Plastic Package)

ORDER CODE : TDA8176

DESCRIPTION
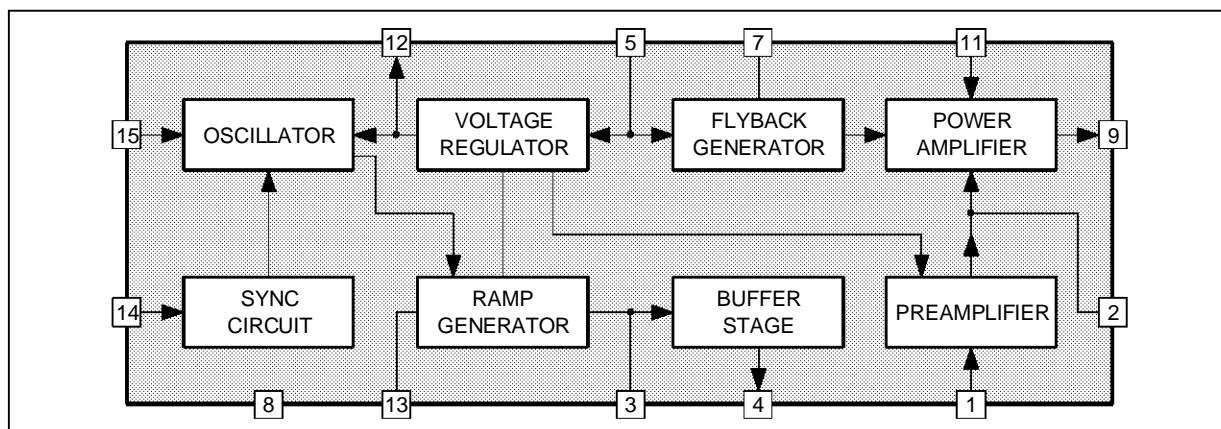
The TDA8176 is a monolithic integrated circuit in Multiwatt 15 package. It is intended for use in color TV sets and monitors.

PIN CONNECTIONS

Pin	Function
15	OSCILLATOR
14	SYNC. INPUT
13	HEIGHT ADJUSTMENT
12	REGULATOR VOLTAGE
11	POWER AMPLIFIER V_S
10	N.C.
9	POWER AMPLIFIER OUT
8	GROUND
7	FLYBACK
6	N.C.
5	VOLTAGE SUPPLY
4	RAMP OUT
3	RAMP GENERATOR
2	COMPENSATION
1	AMPLIFIER

Tab connected to Pin 8

BLOCK DIAGRAM

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_5	Supply Voltage at Pin 2	35	V
V_4, V_5	Flyback Peak Voltage	60	V
V_{10}	Power Amplifier Input Voltage	+ 10 − 0.5	V V
I_o	Output Peak Current (non repetitive) at t = 2 ms	2	A
I_o	Output Peak Current at f = 50 Hz t ≤ 10 μs	2.5	A
I_o	Output Peak Current at f = 50 Hz t > 10 μs	1.5	A
I_3	Pin 3 DC Current at $V_4 < V_2$	100	mA
I_3	Pin 3 Peak to Peak Flyback Current for f = 50 Hz, $t_{fly} ≤ 1.5$ ms	1.8	A
I_8	Pin 8 Current	± 20	mA
P_{tot}	Power Dissipation at T_{tab} = 90 °C at T_{amb} = 80 °C	20 1.4	W W
T_{stg}, T_j	Storage and Junction Temperature	− 40, + 150	°C

8176-01.TBL

THERMAL DATA

Symbol	Parameter		Value	Unit
$R_{th\ (j–c)}$	Thermal Resistance Junction-case	Max.	3	°C/W
$R_{th\ (j–a)}$	Thermal Resistance Junction-ambient	Max.	50	°C/W

8176-02.TBL

AC ELECTRICAL CHARACTERISTICS

(refer to the test circuit, V_S = 25V ; f = 50Hz ; T_{amb} = 25°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_s	Supply Current	I_y = 1 App		140		mA
I_{14}	Sync. Input Current (positive or negative)		500			μA
V_9	Flyback Voltage	I_y = 1 App		51		V
V_{15}	Peak to peak Oscillator Sawtooth Voltage			2.4		V
t_{fly}	Flyback Time	I_y = 1 App		0.7		ms
f_o	Free Running Frequency	($P_1 + R_1$) = 300kΩ C_2 = 100 nF		44		Hz
		($P_1 + R_1$) = 260kΩ C_2 = 100 nF		52		Hz
Δf	Synchronization Range	I_8 = 0.5 mA	14			Hz
$\dfrac{\Delta f}{\Delta V_S}$	Frequency Drift with Supply Voltage	V_s = 10 to 35 V		0.005		Hz/V
$\left\|\dfrac{\Delta f}{\Delta T_{tab}}\right\|$	Frequency Drift with Tab Temperature	T_{tab} = 40 to 120 °C		0.01		Hz/°C

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DC ELECTRICAL CHARACTERISTICS (V_S = 35V, T_{amb} = 25°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_5	Pin 5 Quiescent Current	$I_7 = 0$		7	14	mA
I_{11}	Pin 11 Quiescent Current	$I_9 = 0$		8	17	mA
$-I_{15}$	Oscillator Bias Current	$V_{15} = 1$ V		0.1	1	μA
$-I_1$	Amplifier Input Bias Current	$V_1 = 1$ V		0.1	10	μA
$-I_3$	Ramp Generator Bias Current	$V_3 = 0$		0.02	0.3	μA
$-I_3$	Ramp Generator Current	$I_{13} = 20$ μA, $V_3 = 0$	18.5	20	21.5	μA
$\dfrac{\Delta I_3}{I_3}$	Ramp Generator Non-linearity	$\Delta V_{12} = 0$ to 12 V $I_{13} = 20$ μA		0.2	1	%
V_s	Supply Voltage Range		10		35	V
V_4	Pin 4 Saturation Voltage to Ground	$I_4 = 1$ mA		1	1.4	V
V_7	Pin 7 Saturation Voltage to Ground	$I_7 = 10$ mA		300	450	mV
V_9	Quiescent Output Voltage	$V_s = 10$ V $R_1 = 10$ kΩ $R_2 = 10$ kΩ	4.1	4.4	4.75	V
		$V_s = 35$ V $R_1 = 30$ kΩ $R_2 = 10$ kΩ	8.3	8.8	9.45	V
V_{9L}	Output Saturation Voltage to Ground	$-I_9 = 0.1$ A		0.9	1.2	V
		$-I_9 = 0.8$ A		1.9	2.3	V
V_{9H}	Output Saturation Voltage to Supply	$I_9 = 0.1$ A		1.4	2.1	V
		$I_9 = 0.8$ A		2.8	3.2	V
V_{12}	Regulated Voltage at Pin 12		6.1	6.5	6.9	V
V_{13}	Regulated Voltage at Pin 13	$I_{13} = 10$ μA	6.2	6.6	7	V
$\dfrac{\Delta V_{12}}{\Delta V_S}, \dfrac{\Delta V_{13}}{\Delta V_S}$	Regulated Voltage Drift with Supply Voltage	$\Delta V_s = 10$ to 35 V		1		mV/V
V_1	Amplifier Input Reference Voltage		2.07	2.2	2.3	V
R_{14}	Pin 8 Input Resistance	$V_{14} \leq 0.4$ V	1			MΩ

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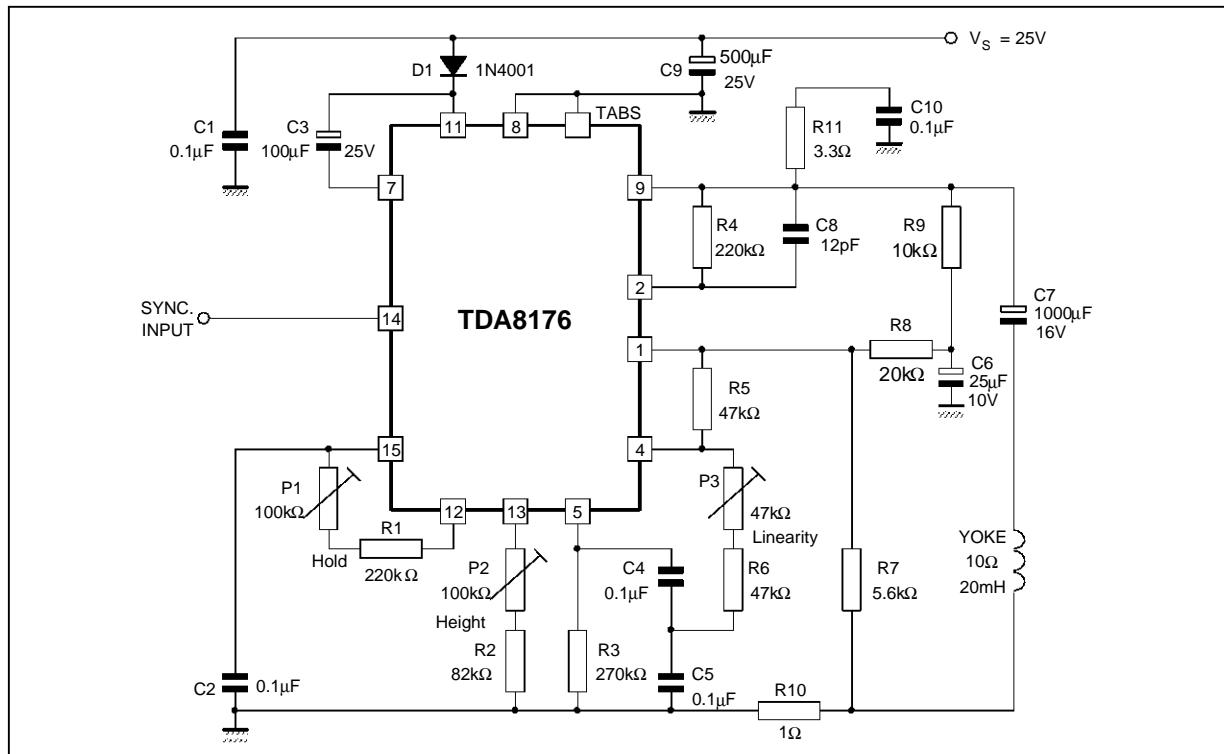
TYPICAL PERFORMANCE OF THE CRCUIT OF FIG.1

Symbol	Parameter	Value	Unit
V_S	Operating Supply Voltage	25	V
I_S	Supply Current	175	mA
t_{fly}	Flyback Time	1	ms
P_{tot}	Power Dissipation	3.25	W
i_y	Maximum Scanning Current (peak-to-peak)	1.4	A

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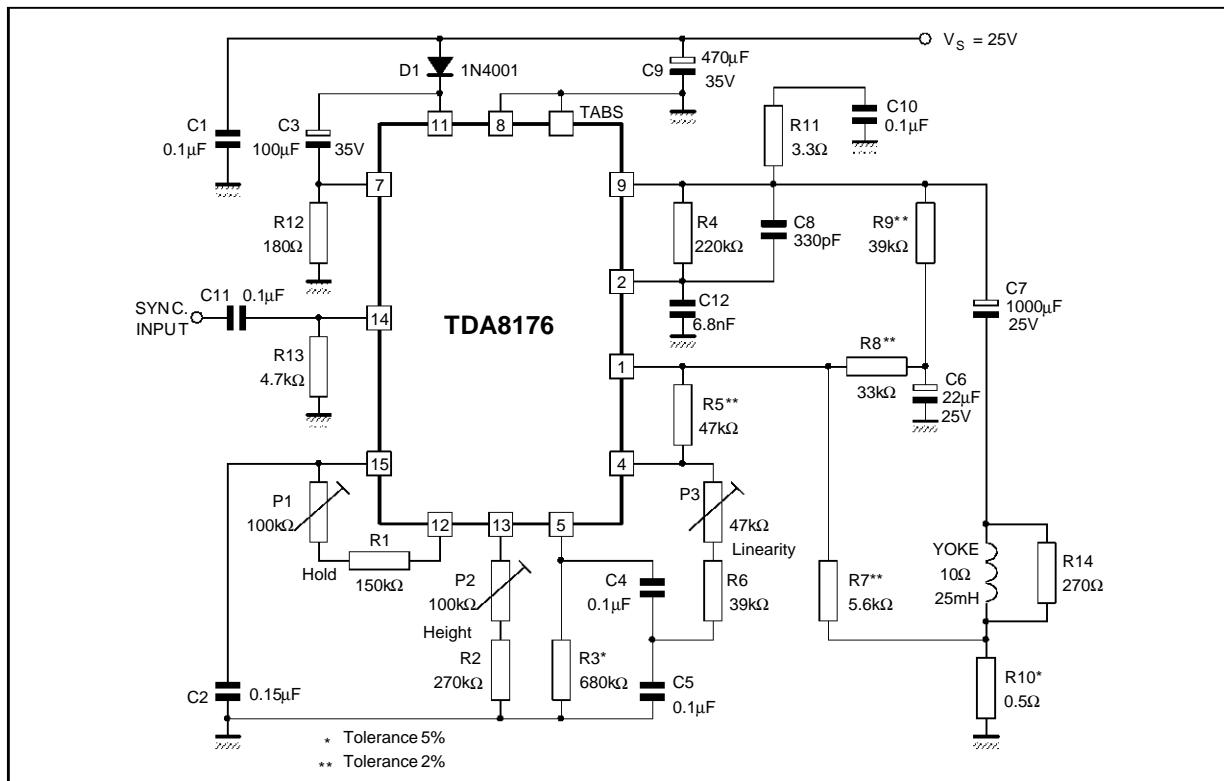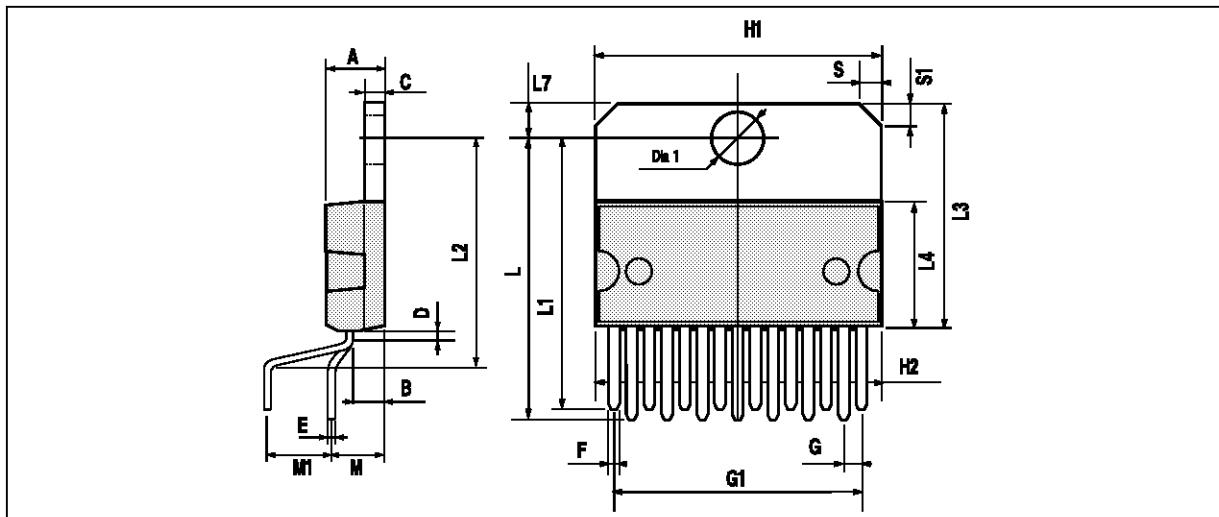
AC TEST CIRCUITS

Figure 1 :   Typical Application Circuit for large Screen 110° PIL TVC Set (Ry = 10 Ω ;
Ly = 25 mH ; Iy = 1.25 App).

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PACKAGE MECHANICAL DATA : 15 PINS - PLASTIC MULTIWATT

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5			0.197
B			2.65			0.104
C			1.6			0.063
D		1			0.039	
E	0.49		0.55	0.019		0.022
F	0.66		0.75	0.026		0.030
G	1.14	1.27	1.4	0.045	0.050	0.055
G1	17.57	17.78	17.91	0.692	0.700	0.705
H1	19.6			0.772		
H2			20.2			0.795
L	22.1		22.6	0.870		0.890
L1	22		22.5	0.866		0.886
L2	17.65		18.1	0.695		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
M	4.2	4.3	4.6	0.165	0.169	0.181
M1	4.5	5.08	5.3	0.177	0.200	0.209
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia. 1	3.65		3.85	0.144		0.152

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